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Low Phase Noise VCXO (9.5-65MHz)

FEATURES

- 19MHz to 65MHz fundamental crystal input.
- Output range: 9.5MHz – 65MHz
- Complementary outputs: PECL or LVDS output.
- Selectable OE Logic (enable high or enable low).
- Available outputs: PECL, LVDS, or CMOS (High Drive (30mA) or Standard Drive (10mA) output).
- Integrated variable capacitors.
- Supports 2.5V or 3.3V Power Supply.
- Available in die form.

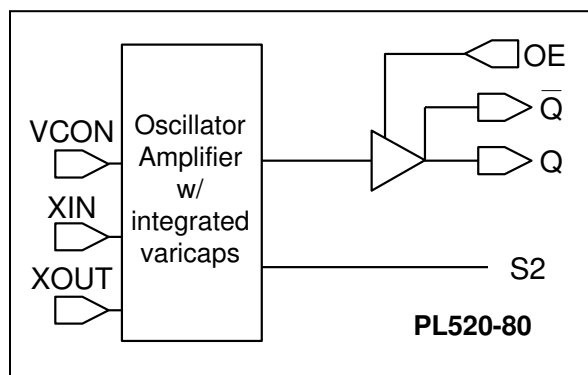
DESCRIPTION

The PL520-80 is a VCXO IC specifically designed to work with fundamental crystals between 19MHz and 65MHz. The selectable divide by two feature extends the operation range from 9.5MHz to 65MHz. It requires very low current into the crystal resulting in better overall stability. The OE logic feature allows selection of enable high or enable low. Furthermore, it provides selectable CMOS, PECL or LVDS outputs.

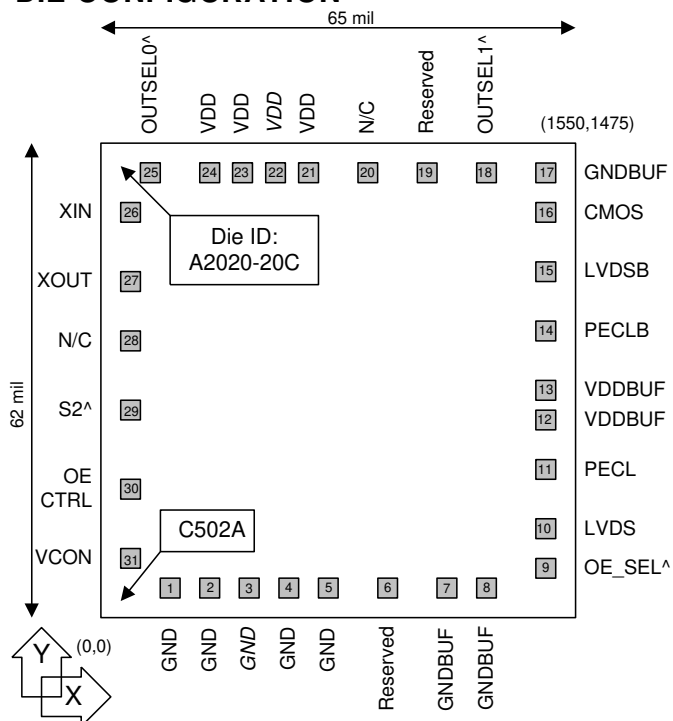
DIE SPECIFICATIONS

Name	Value
Size	62 x 65 mil
Reverse side	GND
Pad dimensions	80 micron x 80 micron
Thickness	10 mil

BLOCK DIAGRAM



DIE CONFIGURATION



OUTPUT SELECTION AND ENABLE

OUT_SEL1* (Pad 18)	OUT_SEL0* (Pad 25)	Selected Output*
0	0	High Drive CMOS
0	1	Standard CMOS
1	0	LVDS
1	1	PECL (default)

OE_SELECT (Pad 9)	OE_CTRL (Pad 30)	State
0	0	Tri-state
	1 (Default)	Output enabled
1 (Default)	0 (Default)	Output enabled
	1	Tri-state

Pads #9, #18 & #25: Bond to GND to set to "0",
No connection results to "default" setting through internal pull-up.

OE_CTRL: Logical states defined by PECL levels if OE_SELECT is "1"
Logical states defined by CMOS levels if OE_SELECT is "0"

OUTPUT FREQUENCY SELECTOR

S2	Output
0	Input/2
1(Default)*	Input

*Internally set to 'Default' through 60KΩ pull-up resistor

ELECTRICAL SPECIFICATIONS

1. Absolute Maximum Ratings

PARAMETERS	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage	V_{DD}		4.6	V
Input Voltage, dc	V_I	-0.5	$V_{DD}+0.5$	V
Output Voltage, dc	V_O	-0.5	$V_{DD}+0.5$	V
Storage Temperature	T_S	-65	150	°C
Ambient Operating Temperature*	T_A	-40	85	°C
Junction Temperature	T_J		125	°C
Lead Temperature (soldering, 10s)			260	°C
ESD Protection, Human Body Model			2	kV

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

* Note: Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for COMMERCIAL grade only.

2. Crystal Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Crystal Resonator Frequency	F_{XIN}	Fundamental	19		65	MHz
Crystal Loading Rating	$C_L (xtal)$	Die		8*		pF
Interelectrode Capacitance	C_0				5	pF
Recommended ESR	R_E	AT cut			30	Ω

Note: Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits.

3. Voltage Control Crystal Oscillator

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
VCXO Stabilization Time *	$T_{VCXOSTB}$	From power valid			10	ms
VCXO Tuning Range		$F_{XIN} = 19 - 65\text{MHz};$ $XTAL C_0/C_1 < 250$ $0V \leq VCON \leq 3.3V$		200*		ppm
CLK output pullability		$VCON = 1.65V, \pm 1.65V$	$\pm 100^*$			ppm
On-chip Varicaps control range		$VCON = 0 \text{ to } 3.3V$		4 – 18*		pF
Linearity					10*	%
VCXO Tuning Characteristic				65		ppm/V
VCON input impedance				60		k Ω
VCON modulation BW		$0V \leq VCON \leq 3.3V, -3dB$	25			kHz

Note: Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits.

Low Phase Noise VCXO (9.5-65MHz)
4. General Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Supply Current (Loaded Outputs)	I _{DD}	PECL/LVDS/CMOS			100/80/40	mA
Operating Voltage	V _{DD}		2.97		3.63	V
Output Clock Duty Cycle		@ 50% V _{DD} (CMOS) @ 1.25V (LVDS) @ V _{DD} – 1.3V (PECL)	45 45 45	50 50 50	55 55 55	%
Short Circuit Current				±50		mA

5. Jitter Specifications

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Period jitter RMS at 27MHz	With capacitive decoupling between VDD and GND. Over 10,000 cycles		2.3		ps
Period jitter peak-to-peak at 27MHz			18.5	20	
Accumulated jitter RMS at 27MHz	With capacitive decoupling between VDD and GND. Over 1,000,000 cycles.		2.3		ps
Accumulated jitter peak-to-peak at 27MHz			24	25	
Random Jitter	"RJ" measured on Wavecrest SIA 3000		2.3		ps

Measured on Wavecrest SIA 3000

6. Phase Noise Specifications

PARAMETERS	FREQUENCY	@10Hz	@100Hz	@1kHz	@10kHz	@100kHz	UNITS
Phase Noise relative to carrier	27MHz	-75	-100	-125	-140	-145	dBc/Hz

Note: Phase Noise measured on Agilent E5500

7. CMOS Output Electrical Specifications

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output drive current (High Drive)	I _{OH}	V _{OH} = V _{DD} -0.4V, V _{DD} =3.3V	30			mA
	I _{OL}	V _{OL} = 0.4V, V _{DD} = 3.3V	30			
Output drive current (Standard Drive)	I _{OH}	V _{OH} = V _{DD} -0.4V, V _{DD} =3.3V	10			
	I _{OL}	V _{OL} = 0.4V, V _{DD} = 3.3V	10			
Output Clock Rise/Fall Time (High Drive)	t _r / t _f	0.3V ~ 3.0V with 15 pF load		1.2		ns
Output Clock Rise/Fall Time (Standard Drive)	t _r / t _f	0.3V ~ 3.0V with 15 pF load		2.4		

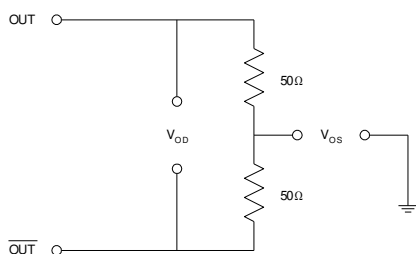
8. LVDS Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Differential Voltage	V_{OD}	$R_L = 100\ \Omega$ (see figure)	247	355	454	mV
V_{DD} Magnitude Change	ΔV_{OD}		-50		50	mV
Output High Voltage	V_{OH}			1.4	1.6	V
Output Low Voltage	V_{OL}		0.9	1.1		V
Offset Voltage	V_{OS}		1.125	1.2	1.375	V
Offset Magnitude Change	ΔV_{OS}		0	3	25	mV
Power-off Leakage	I_{OXD}	$V_{out} = V_{DD}$ or GND $V_{DD} = 0V$		± 1	± 10	μA
Output Short Circuit Current	I_{OSD}			-5.7	-8	mA

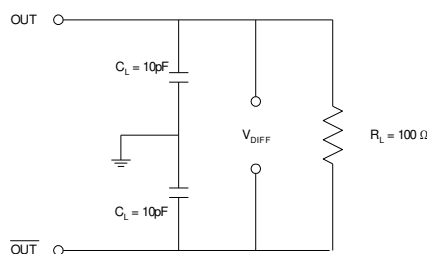
9. LVDS Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Differential Clock Rise Time	t_r	$R_L = 100\ \Omega$ $C_L = 10\ pF$ (see figure)	0.2	0.7	1.0	ns
Differential Clock Fall Time	t_f		0.2	0.7	1.0	ns

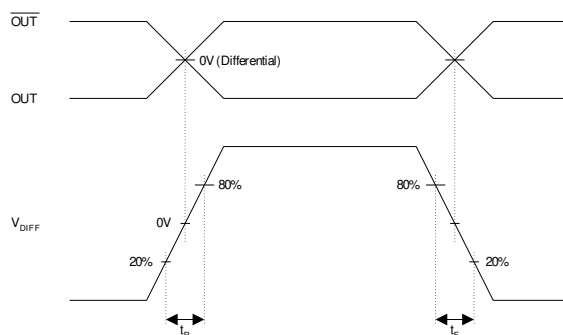
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transition Time Waveform

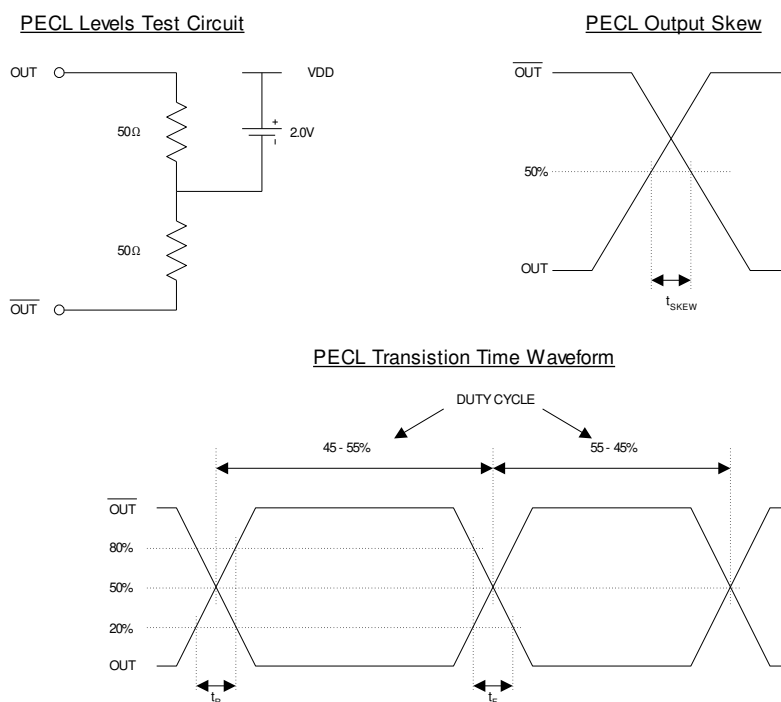


10. PECL Electrical Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	MAX.	UNITS
Output High Voltage	V_{OH}	$R_L = 50\ \Omega$ to ($V_{DD} - 2V$) (see figure)	$V_{DD} - 1.025$		V
Output Low Voltage	V_{OL}			$V_{DD} - 1.620$	V

11. PECL Switching Characteristics

PARAMETERS	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Clock Rise Time	t_r	@20/80% - PECL		0.6	1.5	ns
Clock Fall Time	t_f	@80/20% - PECL		0.5	1.5	ns



Low Phase Noise VCXO (9.5-65MHz)
PAD DESCRIPTIONS

Pad #	Name	X (μm)	Y (μm)	Description
1	GND	248	109	Ground.
2	GND	361	109	Ground.
3	<i>Optional GND</i>	473	109	Optional Ground.
4	GND	587	109	Ground.
5	GND	702	109	Ground.
6	<i>Reserved</i>	874	109	Reserved for future use.
7	GNDBUF	1042	109	Ground, buffer circuitry.
8	GNDBUF	1171	109	Ground, buffer circuitry.
9	OE_SEL	1400	125	This is the selector input to choose the OE control logic. See the OE SELECTION AND ENABLE table on page 1. Internal pull up.
10	LVDS	1400	259	LVDS output.
11	PECL	1400	476	PECL output.
12	VDDBUF	1400	616	3.3V power supply, buffer circuitry.
13	VDDBUF	1400	716	3.3V power supply, buffer circuitry.
14	PECLB	1400	871	Complementary PECL output.
15	LVDSB	1400	1089	Complementary LVDS output.
16	CMOS	1400	1227	CMOS output.
17	GNDBUF	1389	1365	Ground, buffer circuitry.
18	OUTSEL1	1232	1365	Selector input to choose the selected output type (PECL, LVDS, CMOS). See the OUTPUT SELECTION AND ENABLE table on page 1. Internal pull up.
19	<i>Reserved</i>	1042	1365	Reserved for future use.
20	<i>Not connected</i>	854	1365	Not Connected.
21	VDD	659	1365	3.3V power supply.
22	<i>Optional VDD</i>	559	1365	Optional 3.3V power supply.
23	VDD	459	1365	3.3V power supply.
24	VDD	358	1365	3.3V power supply.
25	OUTSEL0	194	1365	Selector input to choose the selected output type (PECL, LVDS, CMOS). See the OUTPUT SELECTION AND ENABLE table on page 1. Internal pull up.
26	XIN	109	1223	Crystal input. See Crystal Specifications on page 3.
27	XOUT	109	1017	Crystal output. See Crystal Specifications on page 3.
28	<i>Not connected</i>	109	858	Not Connected.
29	S2	109	646	Output Divide by Two selector pin, as presented on the OUTPUT FREQUENCY SELECTOR Table on page 1. Internal pull up.
30	OE_CTRL	109	397	Used to enable/disable the output(s). See Output Selection and Enable table on page 1.
31	VCON	109	181	Voltage control input. 0V to 3.3V.

Note: for optimal Phase Noise performance, it is recommended to bond all optional VDD and GND pads.

ORDERING INFORMATION

For part ordering, please contact our Sales Department:

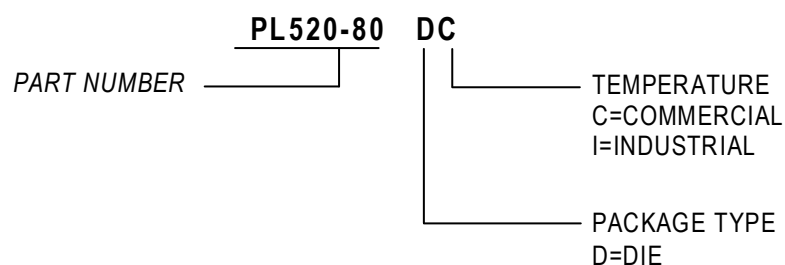
2180 Fortune Drive, San Jose, CA 95131, USA

Tel: (408) 944-0800 Fax: (408) 474-1000

PART NUMBER

The order number for this device is a combination of the following:

Device number, Package type and Operating temperature range



<u>Order Number</u>	<u>Marking</u>	<u>Package Option</u>
PL520-80DC	P520-80DC	Die – Waffle Pack

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